

Sample &

Buv



SN74LVC1G00

SCES212AB-APRIL 1999-REVISED APRIL 2014

SN74LVC1G00 Single 2-Input Positive-NAND Gate

Technical

Documents

Features 1

- Available in the Ultra Small 0.64-mm² Package (DPW) With 0.5-mm Pitch
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Provides Down Translation to V_{CC}
- Max t_{pd} of 3.8 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 1000-V Charged-Device Model (C101)

Applications 2

- **AV Receiver**
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- MP3 Player/Recorder (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse

Simplified Schematic 4



3 Description

Tools &

Software

This single 2-input positive-NAND gate is designed for 1.65-V to 5.5-V V_{CC} operation.

Support &

Community

...

The SN74LVC1G00 performs the Boolean function $Y = \overline{A \times B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

The CMOS device has high output drive while maintaining low static power dissipation over a broad V_{CC} operating range.

The SN74LVC1G00 is available in a variety of packages, including the ultra-small DPW package with a body size of $0.8 \text{ mm} \times 0.8 \text{ mm}$.

Device Information⁽¹⁾

DEVICE NAME	PACKAGE	BODY SIZE	
	SOT-23 (5)	2.9mm × 1.6mm	
	SC70 (5)	2.0mm × 1.25mm	
SN74LVC1G00	X2SON (4)	0.8mm × 0.8mm	
	SON (6)	1.45mm × 1.0mm	
	DSBGA (5)	1.41mm × 0.91mm	

(1) For all available packages, see the orderable addendum at the end of the datasheet.



Table of Contents

9

10.2

12.1

14

1	Feat	ures 1
2	Арр	lications 1
3	Des	cription 1
4	Sim	plified Schematic 1
5	Revi	ision History 2
6	Pin	Configuration and Functions
7	Spe	cifications
	7.1	Absolute Maximum Ratings 3
	7.2	Handling Ratings 3
	7.3	Recommended Operating Conditions 4
	7.4	Thermal Information 4
	7.5	Electrical Characteristics5
	7.6	Switching Characteristics, $C_L = 15 \text{ pF} \dots 5$
	7.7	Switching Characteristics, -40°C to 85°C5
	7.8	Switching Characteristics, -40°C to 125°C 5
	7.9	Operating Characteristics 6
	7.10	Typical Characteristics 6
8	Para	meter Measurement Information

Revision History 5

2

CI	hanges from Revision AA (March 2014) to Revision AB	Page
•	Added Pin Functions table.	3
•	Updated Handling Ratings table.	
•	Added Thermal Information table.	4
•	Added Typical Characteristics.	
•	Added Detailed Description section.	
•	Added Application and Implementation section.	10
•	Added Power Supply Recommendations section.	11
•	Added Layout section.	11

Changes from Revision Z (November 2014) to Revision AA

•	Added Applications section.	1
•	Added Device Information table.	1
•	Added T _{stg} to Handling Ratings table.	3

Changes from Revision Y (September 2013) to Revision Z

Submit Documentation Feedback

Changed document Features		
Changes from Revision X (November 201	2) to Revision Y	Page
 Extended operating temperature from 85 	5°C to 125°C	

Page

www.ti.com

STRUMENTS

XAS

10 Application and Implementation...... 10 10.1 Application Information..... 10

Typical Application 10

Layout Guidelines 11

12.2 Layout Example 11 13 Device and Documentation Support 12 13.1 Trademarks 12 13.2 Electrostatic Discharge Caution 12 13.3 Glossary 12

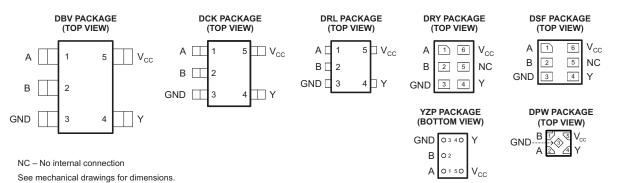
Information 12

11 Power Supply Recommendations 11 12 Layout...... 11

Mechanical, Packaging, and Orderable



6 Pin Configuration and Functions



Pin Functions

PIN				
NAME	DBV, DCK, DRL, YZP	DRY, DSF	DPW	DESCRIPTION
А	1	1	2	Input
В	2	2	1	Input
GND	3	3	3	Ground
Y	4	4	4	Output
V _{CC}	5	6	5	Power pin
NC		5		Not connected

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾			6.5	V
Vo	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V_{CC} or GND			±100	mA

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	Storage temperature range			
V _(ESD)	Electrostatia discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	M
	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1000	v

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

SN74LVC1G00

SCES212AB-APRIL 1999-REVISED APRIL 2014

www.ti.com

STRUMENTS

EXAS

7.3 Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Cupply voltage	Operating	1.65	5.5	V
V _{IH} V _{IL} V _I V _O I _{OH}	Supply voltage	Data retention only	1.5		v
V _{IH} H V _{IL} L V _{IL} L V _O G I _{OH} H I _{OL} L Δt/Δv I		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
	Lligh lovel input veltage	$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	1.7		V
	High-level input voltage	$V_{CC} = 3 V \text{ to } 3.6 V$	2		v
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V	$0.7 \times V_{CC}$		
V _{IH} V _{IL} V _O		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
		$V_{CC} = 2.3 \text{ V}$ to 2.7 V		0.7	V
۷IL	Low-level input voltage	$V_{CC} = 3 V$ to 3.6 V		0.8	v
		$V_{CC} = 4.5 V$ to 5.5 V		$0.3 \times V_{CC}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
V _{IH} V _{IL} V _I V ₀ I _{OH} I _{OL}		V _{CC} = 1.65 V		-4	
	High-level output current	V _{CC} = 2.3 V		-8	
		V _{CC} = 3 V		-16	mA
		V _{CC} = 3 V		-24	
	$'_{1H}$ High-level input voltage $'_{1L}$ Low-level input voltage $'_{1L}$ Input voltage $'_{O}$ Output voltage O_{OH} High-level output current O_{DL} Low-level output current O_{DL} Low-level output current O_{L} Input transition rise or fall rate	$V_{CC} = 4.5 V$		-32	
V _I V _O I _{OH}		V _{CC} = 1.65 V		4	
		V _{CC} = 2.3 V		8	
I _{OL}	Low-level output current	V _{CC} = 3 V		16	mA
		VCC - 5 V		24	
		$V_{CC} = 4.5 V$		32	
		V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5	
T _A	Operating free-air temperature		-40	125	°C

 All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

7.4 Thermal Information

		SN74LVC1G00							
THERMAL METRIC ⁽¹⁾		DBV	DCK	DRL	DRY	YZP	DPW	UNIT	
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	4 PINS		
R_{\thetaJA}	Junction-to-ambient thermal resistance	229	278	243	439	130	340		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	164	93	78	277	54	215		
$R_{\theta J B}$	Junction-to-board thermal resistance	62	65	78	271	51	294	°C/W	
ψ_{JT}	Junction-to-top characterization parameter	44	2	10	84	1	41	°C/W	
ψ_{JB}	Junction-to-board characterization parameter	62	64	77	271	50	294		
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	250		

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{cc}	-40°0	C to 85°C		RECOI –40°C	UNIT		
				MIN	TYP ⁽¹⁾	MAX	MIN	TYP ⁽¹⁾	MAX	
		I _{OH} = -100 μA	1.65 V to 5.5 V	$V_{CC} - 0.1$			$V_{CC} - 0.1$			
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			1.2			
.,		$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.9			
V _{OH}	I _{OH} = -16 mA	0.1/	2.4			2.4			V	
	$I_{OH} = -24 \text{ mA}$	3 V	2.3			2.3				
		I _{OH} = -32 mA	4.5 V	3.8			3.8			
		I _{OL} = 100 μA	1.65 V to 5.5 V			0.1			0.1	
		$I_{OL} = 4 \text{ mA}$	1.65 V			0.45			0.45	
		I _{OL} = 8 mA	2.3 V			0.3			0.3	v
V _{OL}		I _{OL} = 16 mA	3 V			0.4			0.4	v
		I _{OL} = 24 mA	- 3 V			0.55			0.55	
		I _{OL} = 32 mA	4.5 V			0.55			0.55	
l _l	A or B inputs	V _I = 5.5 V or GND	0 to 5.5 V			±5			±5	μA
I _{off}		$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0			±10			±10	μA
I _{CC}		$V_1 = 5.5 \text{ V or GND}$ $I_0 = 0$	1.65 V to 5.5 V			10		10		μA
ΔI _{CC}		One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND	3 V to 5.5 V			500			500	μA
Ci		V _I = V _{CC} or GND	3.3 V		4			4		pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

7.6 Switching Characteristics, C_L = 15 pF

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

						_40°C	to 85°C						
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V						V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	МАХ	MIN	MAX	MIN	MAX			
t _{pd}	A or B	Y	2.2	7.2	0.9	4.4	0.8	3.8	0.8	3.4	ns		

7.7 Switching Characteristics, -40°C to 85°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 4)

						–40°C	to 85°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	3.1	9	1.3	5.5	1	4.7	1	4	ns

7.8 Switching Characteristics, -40°C to 125°C

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 4)

							MENDED to 125°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	3.1	9.7	1.3	5.8	1	5	1	4.3	ns
t _{pd}	Α	Y	2	6.4	1	4.2	0.7	3.3	0.7	3.1	ns

SN74LVC1G00

SCES212AB-APRIL 1999-REVISED APRIL 2014



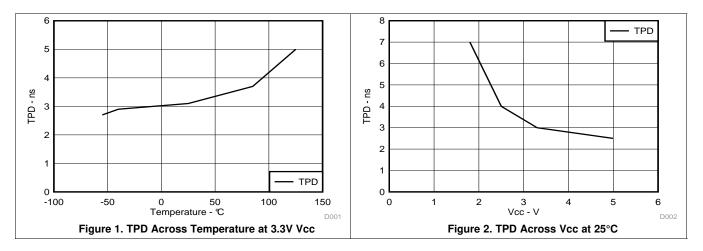
www.ti.com

7.9 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	22	22	23	25	pF

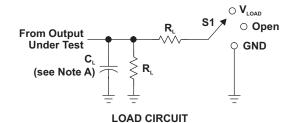
7.10 Typical Characteristics



Copyright © 1999–2014, Texas Instruments Incorporated

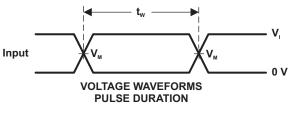


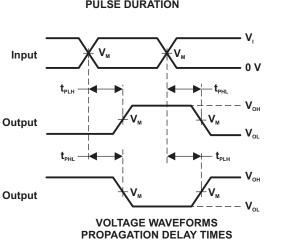
8 Parameter Measurement Information



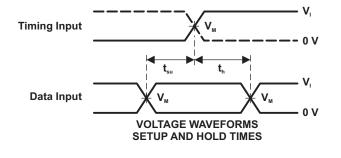
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	VLOAD
t _{PHZ} /t _{PZH}	GND

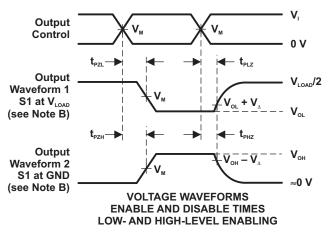
	INF	PUTS		N		-	N
V _{cc}	V	t,/t,	V _M	VLOAD	CL	R	V _A
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.15 V
$2.5 V \pm 0.2 V$	V_{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.15 V
$3.3 V \pm 0.3 V$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 Μ Ω	0.3 V
$5 V \pm 0.5 V$	V_{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.3 V





INVERTING AND NONINVERTING OUTPUTS

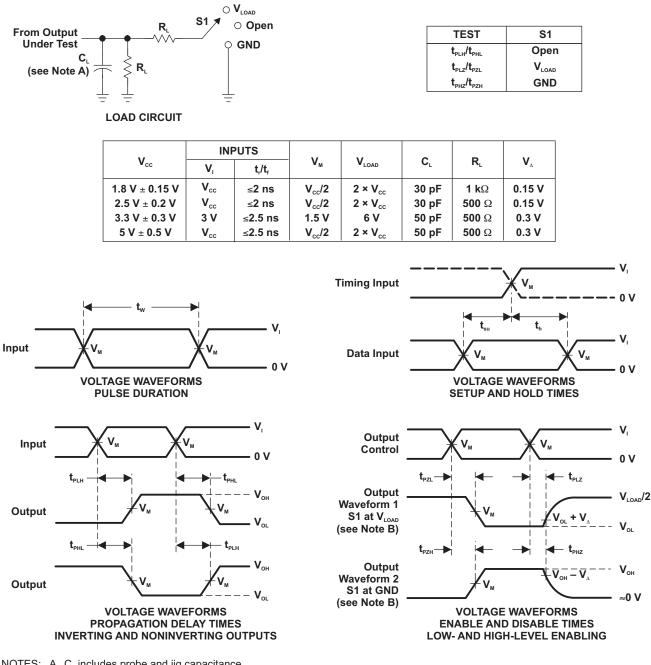




NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{od} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



Parameter Measurement Information (continued)

NOTES: A. C_{L} includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_o = 50 Ω .

- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. $t_{_{PZL}}$ and $t_{_{PZH}}$ are the same as $t_{_{en}}$.
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

www.ti.com



9 Detailed Description

9.1 Overview

SCES212AB – APRIL 1999 – REVISED APRIL 2014

The <u>SN74LVC1G00</u> device contains one 2-input positive-NAND gate and performs the Boolean function $Y = \overline{A \times B}$ or $Y = \overline{A} + \overline{B}$. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

9.2 Functional Block Diagram



9.3 Feature Description

- Wide operating voltage range.
 - Operates from 1.65 V to 5.5 V.
- Allows down voltage translation.
- Inputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

9.4 Device Functional Modes

	Function Table	
INF	PUTS	OUTPUT
А	В	Y
Н	Н	L
L	Х	н
Х	L	н

Copyright © 1999–2014, Texas Instruments Incorporated

SN74LVC1G00 SCES212AB – APRIL 1999 – REVISED APRIL 2014

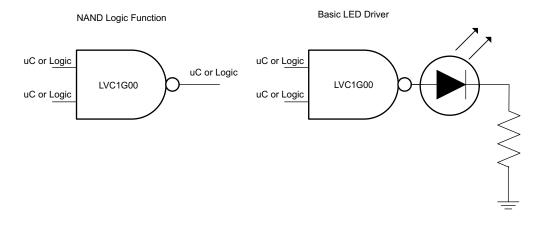
www.ti.com

10 Application and Implementation

10.1 Application Information

The SN74LVC1G00 is a high drive CMOS device that can be used for implementing NAND logic with a high output drive, such as an LED application. It can produce 24 mA of drive current at 3.3 V making it Ideal for driving multiple outputs and good for high speed applications up to 100 MHz. The inputs are 5.5 V tolerant allowing it to translate down to V_{CC} .

10.2 Typical Application



10.2.1 Design Requirements

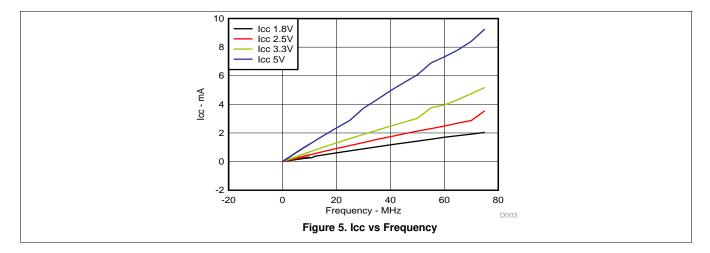
This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs. See ($\Delta t/\Delta V$) in Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V₁ max) in the Recommended Operating Conditions table at any valid V_{CC} .
- 2. Recommend Output Conditions
 - Load currents should not exceed (I_O max) per output and should not exceed total current (continuous current through V_{CC} or GND) for the part. These limits are located in the Absolute Maximum Ratings table.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued) 10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each Vcc pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply a $0.1-\mu$ F capacitor is recommended and if there are multiple Vcc pins then a $0.01-\mu$ F or $0.022-\mu$ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass caps to reject different frequencies of noise. $0.1-\mu$ F and $1-\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to Gnd or Vcc whichever make more sense or is more convenient.

12.2 Layout Example





13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G00DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C005, C00F, C00J, C00K, C00R) (C00H, C00P, C00S)	Samples
SN74LVC1G00DBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C00F	Samples
SN74LVC1G00DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C00F	Samples
SN74LVC1G00DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C005, C00F, C00J, C00K, C00R) (C00H, C00P, C00S)	Samples
SN74LVC1G00DBVTE4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C00F	Samples
SN74LVC1G00DBVTG4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C00F	Samples
SN74LVC1G00DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CA5, CAF, CAJ, CA K, CAR) (CAH, CAP, CAS)	Samples
SN74LVC1G00DCKRE4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA5 CAS	Samples
SN74LVC1G00DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA5 CAS	Samples
SN74LVC1G00DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CA5, CAF, CAJ, CA K, CAR) (CAH, CAP, CAS)	Samples
SN74LVC1G00DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CA5 CAS	Samples
SN74LVC1G00DPWR	ACTIVE	X2SON	DPW	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	H4	Samples
SN74LVC1G00DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(CA7, CAR)	Samples
SN74LVC1G00DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СА	Samples
SN74LVC1G00DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	CA	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G00DSF2	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СА	Samples
SN74LVC1G00DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СА	Samples
SN74LVC1G00YZPR	ACTIVE	DSBGA	YZP	5	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CA7, CAN)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



PACKAGE OPTION ADDENDUM

14-Oct-2022

OTHER QUALIFIED VERSIONS OF SN74LVC1G00 :

Enhanced Product : SN74LVC1G00-EP

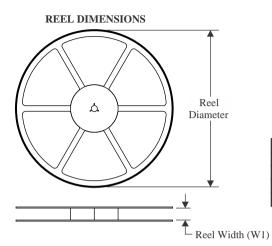
NOTE: Qualified Version Definitions:

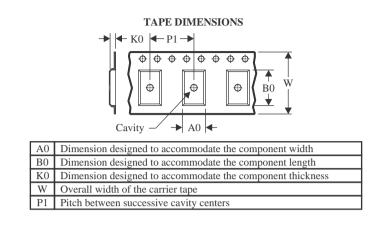
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	-	Package	Pins	SPQ	Reel Diameter	Reel Width	A0	B0	K0	P1	W	Pin1
	Туре	Drawing			(mm)	W1 (mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
SN74LVC1G00DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G00DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G00DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G00DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G00DCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74LVC1G00DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G00DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74LVC1G00DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LVC1G00DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G00DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G00DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74LVC1G00DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G00DRY2	SON	DRY	6	5000	180.0	8.4	1.65	1.2	0.7	4.0	8.0	Q3
SN74LVC1G00DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74LVC1G00DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G00DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3



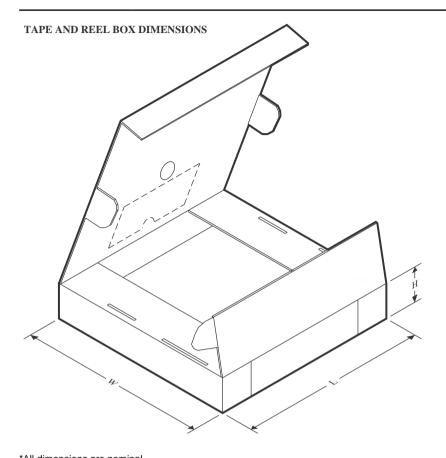
14-Sep-2023

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G00DSF2	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3
SN74LVC1G00DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G00YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1



PACKAGE MATERIALS INFORMATION

14-Sep-2023



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G00DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LVC1G00DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G00DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74LVC1G00DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G00DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
SN74LVC1G00DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G00DCKT	SC70	DCK	5	250	202.0	201.0	28.0
SN74LVC1G00DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G00DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G00DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G00DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74LVC1G00DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G00DRY2	SON	DRY	6	5000	202.0	201.0	28.0
SN74LVC1G00DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G00DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G00DSF2	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G00DSF2	SON	DSF	6	5000	202.0	201.0	28.0
SN74LVC1G00DSFR	SON	DSF	6	5000	184.0	184.0	19.0



PACKAGE MATERIALS INFORMATION

14-Sep-2023

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G00YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0

DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-203.
 Support pin may differ or may not be present.



DCK0005A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0005A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



^{6.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

USON - 0.6 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4207181/G

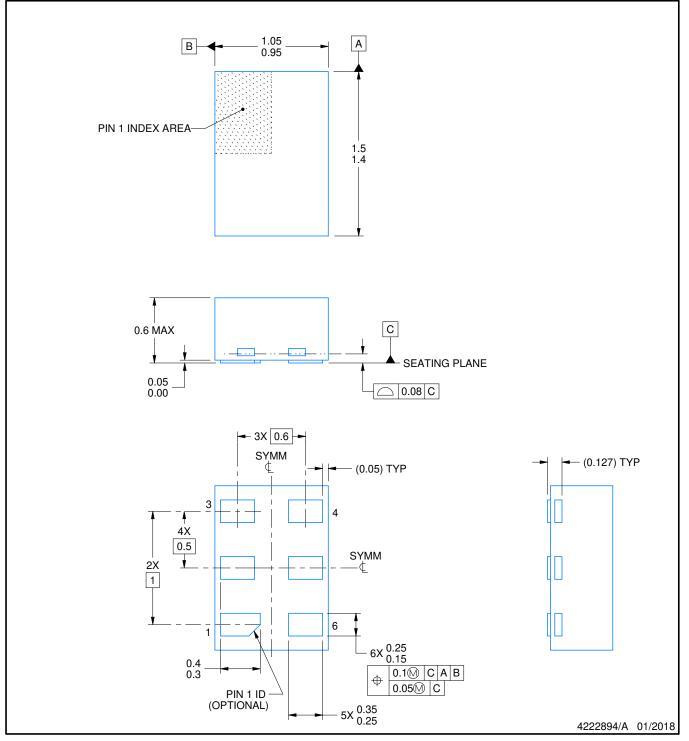
DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

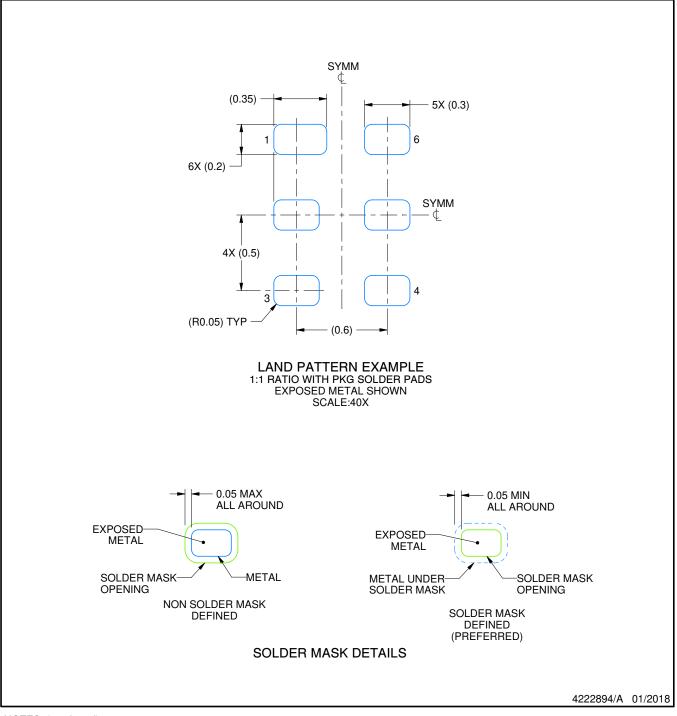


DRY0006A

EXAMPLE BOARD LAYOUT

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).

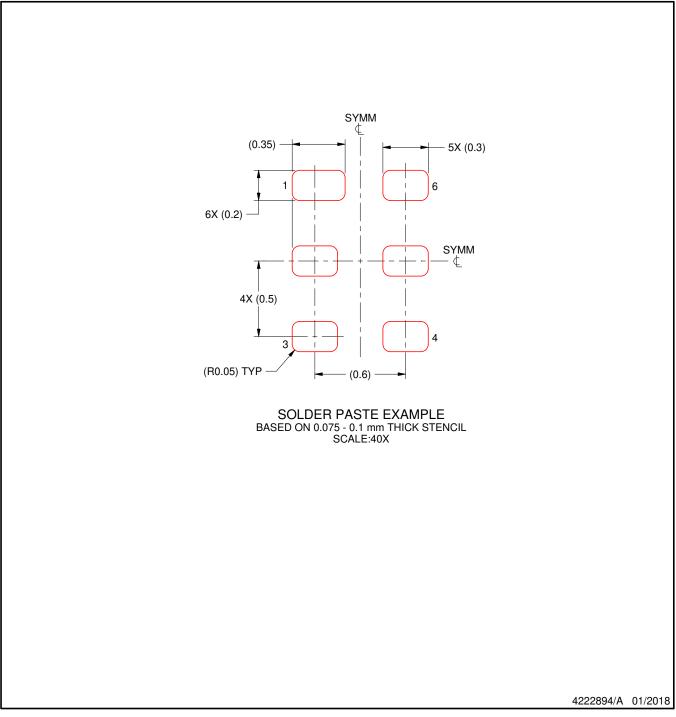


DRY0006A

EXAMPLE STENCIL DESIGN

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



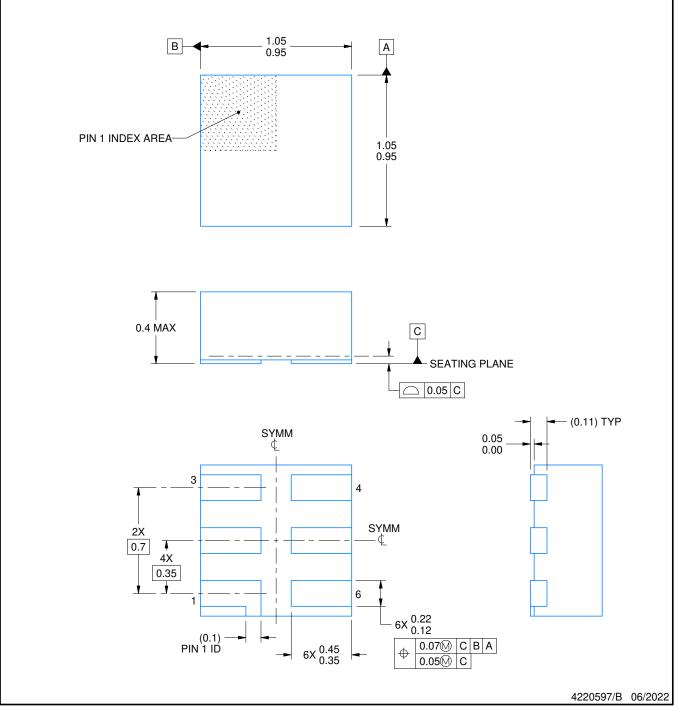
DSF0006A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.

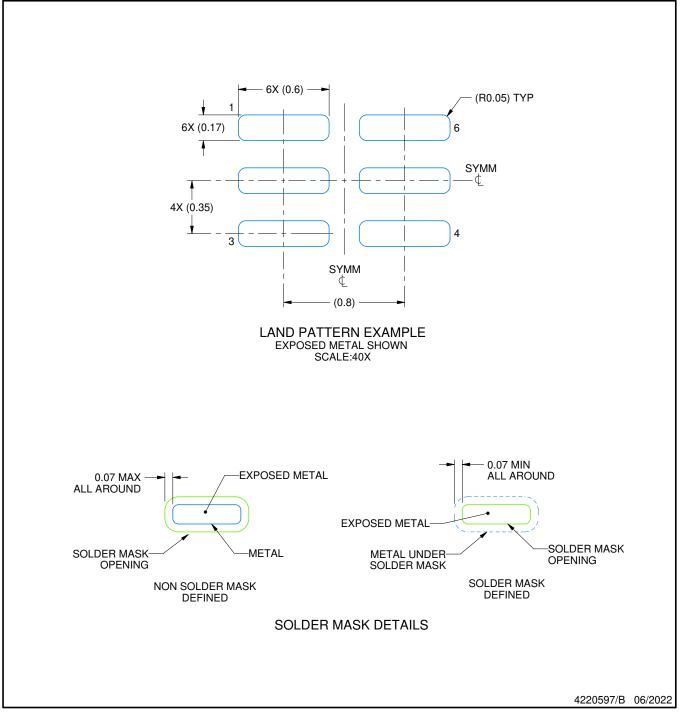


DSF0006A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

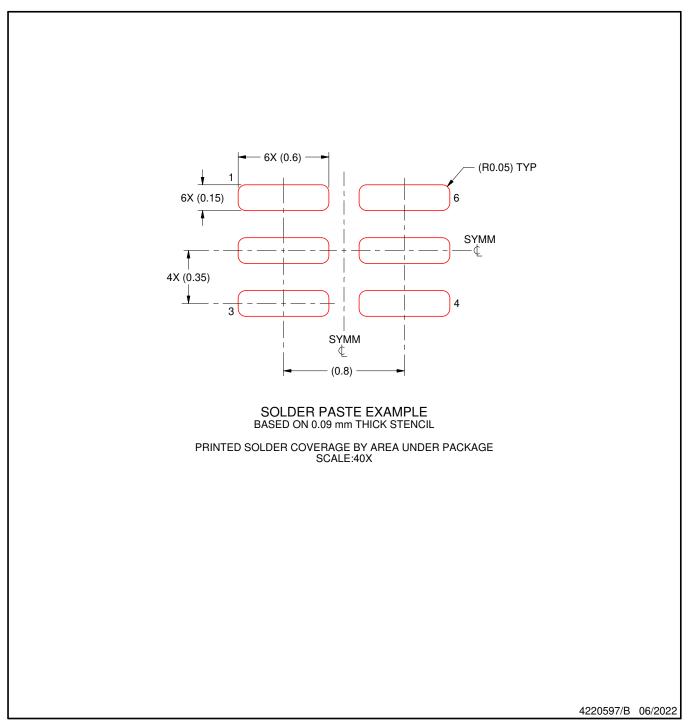


DSF0006A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



GENERIC PACKAGE VIEW

X2SON - 0.4 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4211218-3/D

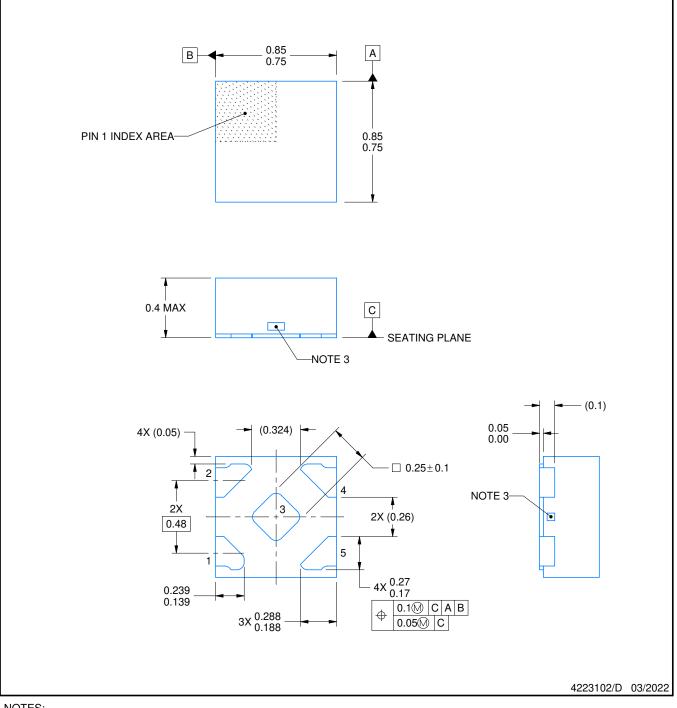
DPW0005A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

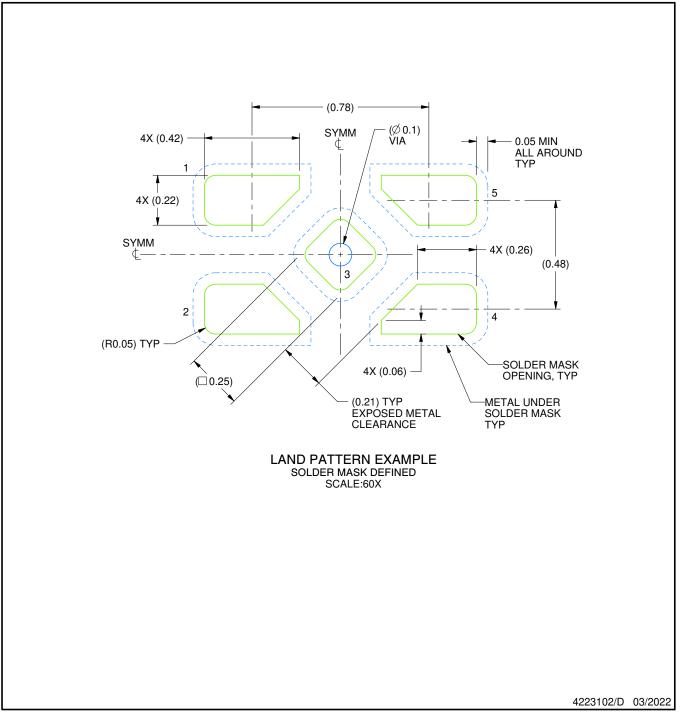


DPW0005A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).

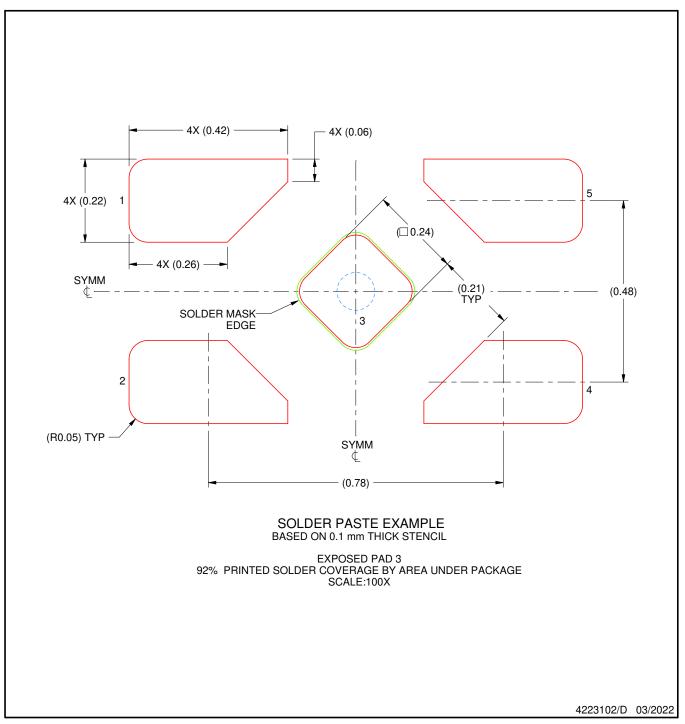


DPW0005A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



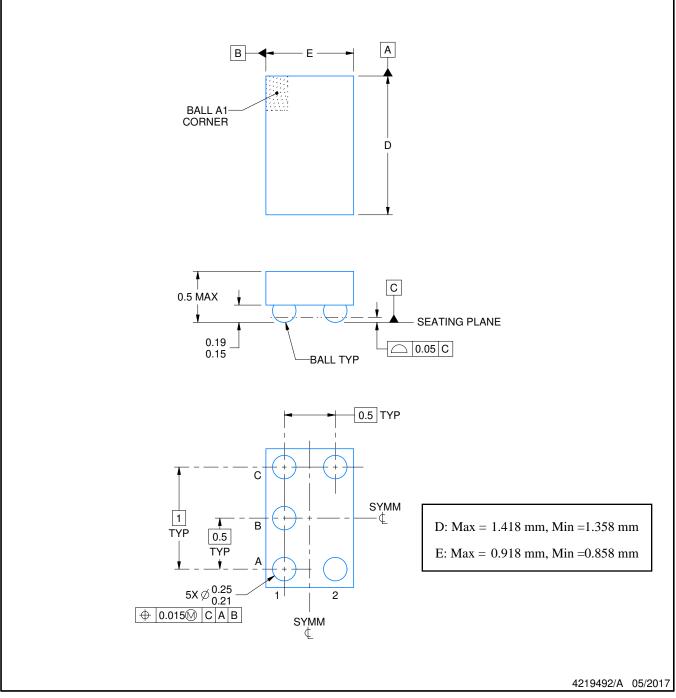
YZP0005



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

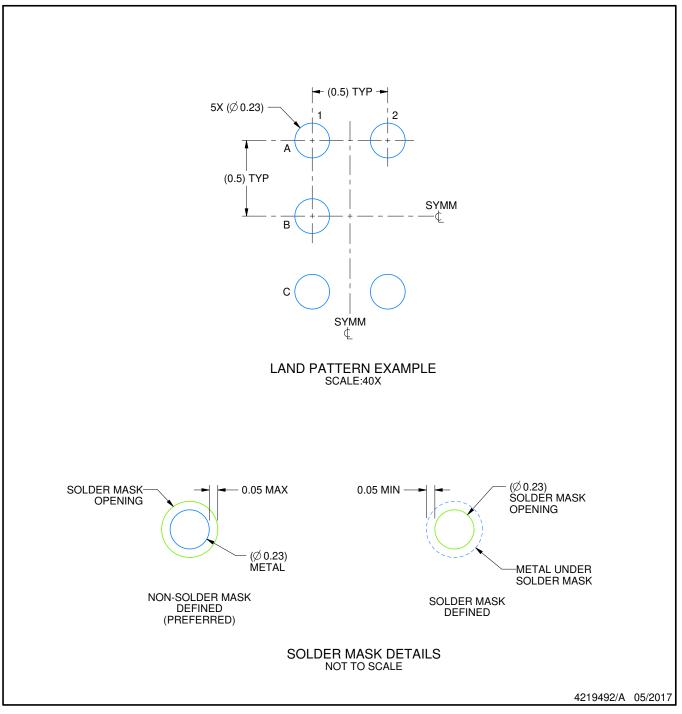


YZP0005

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

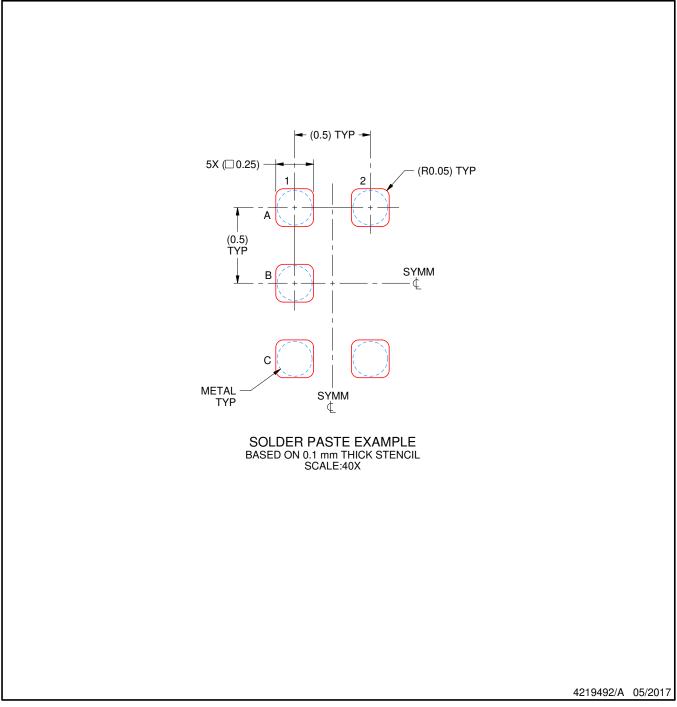


YZP0005

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



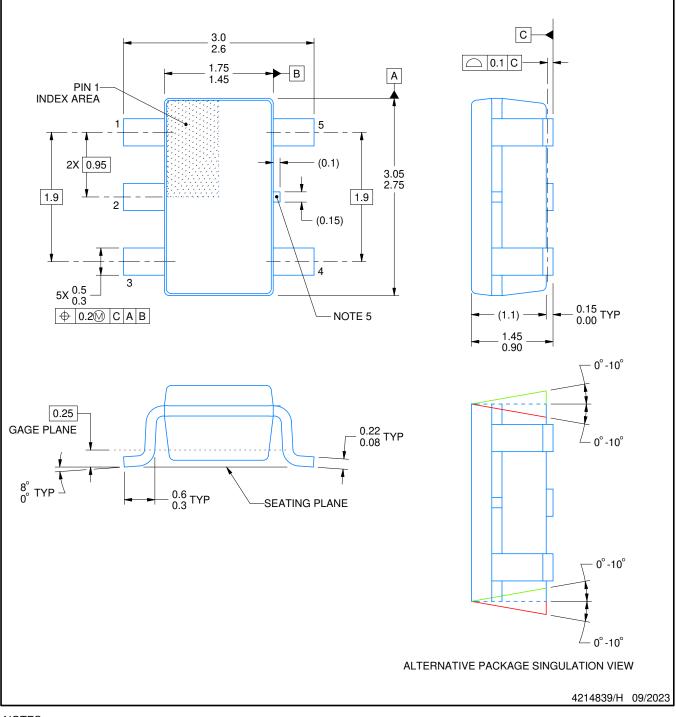
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.This drawing is subject to change without notice.Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.

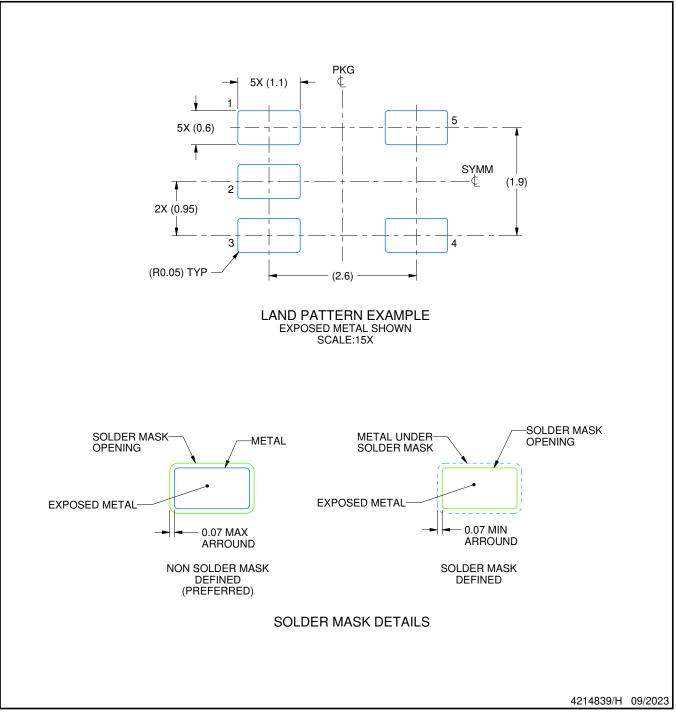


DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

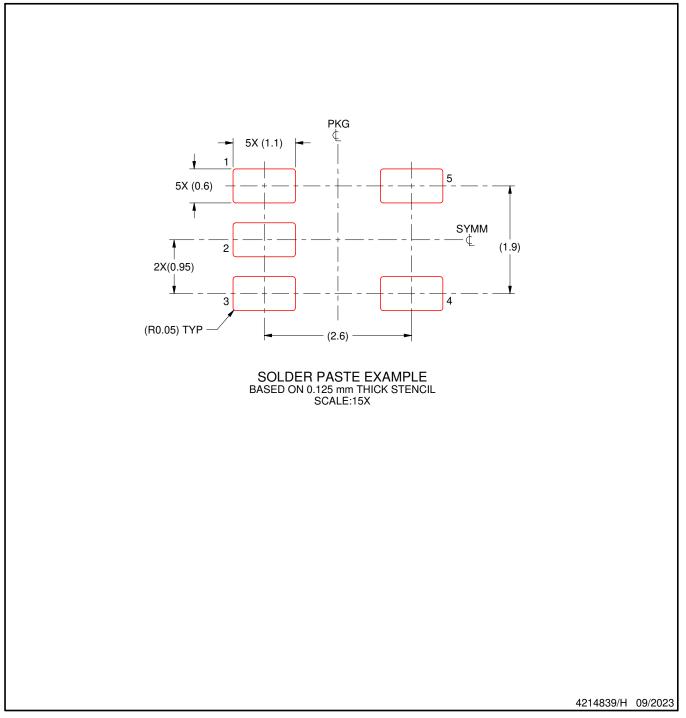


DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



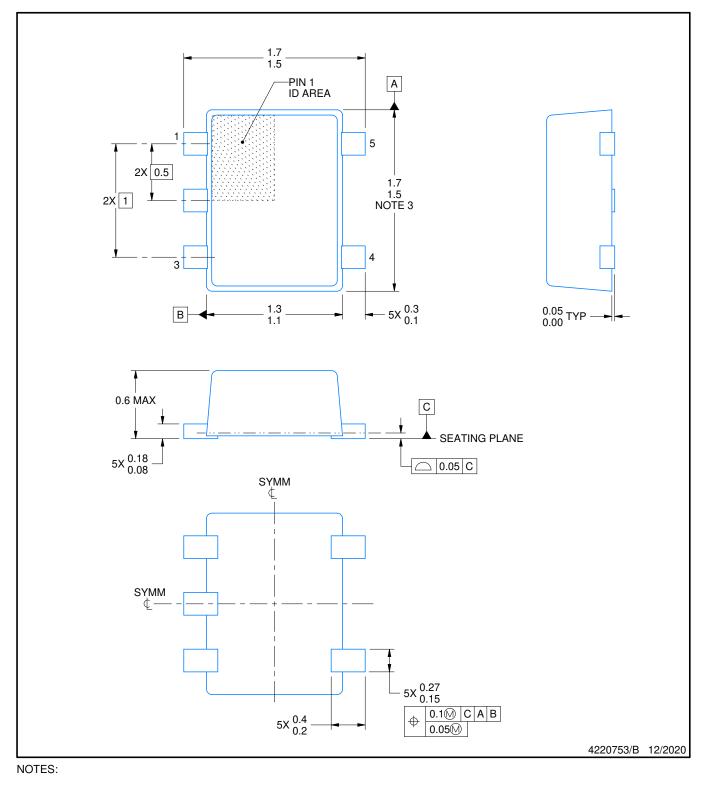
DRL0005A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-293 Variation UAAD-1

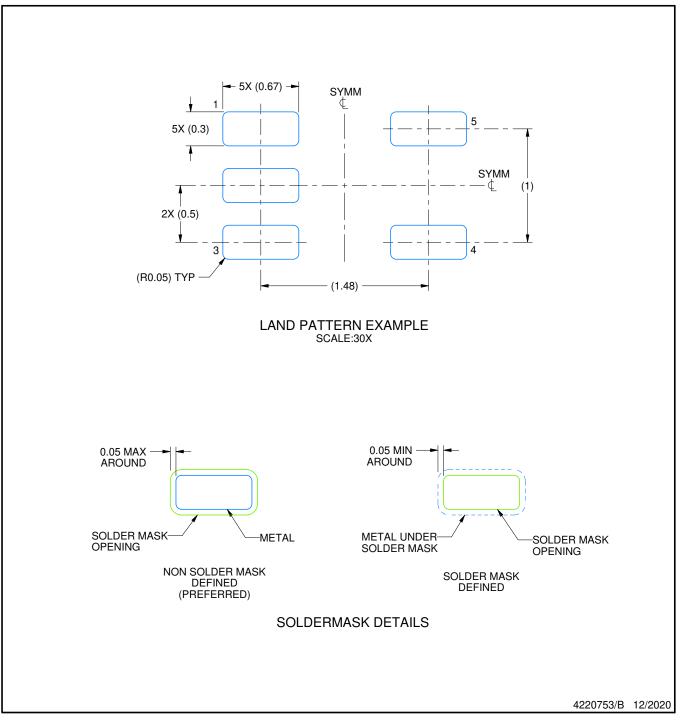


DRL0005A

EXAMPLE BOARD LAYOUT

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

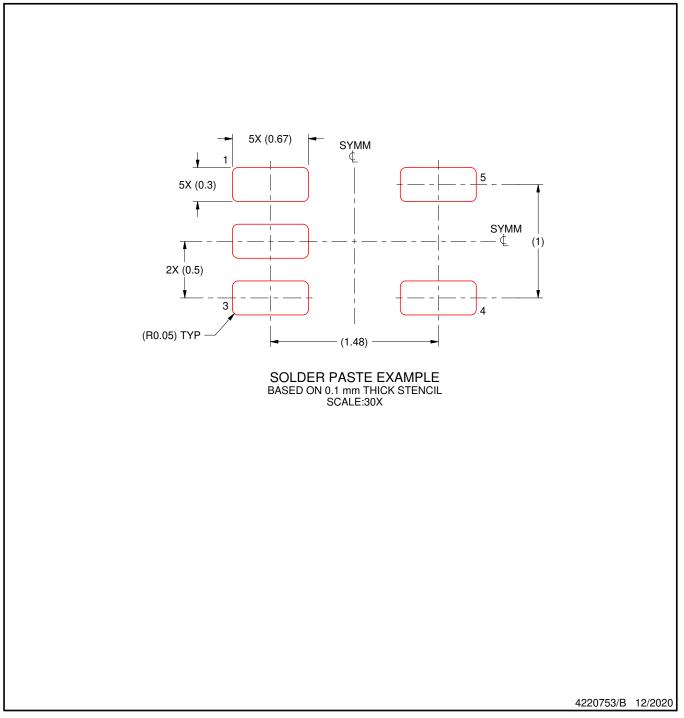


DRL0005A

EXAMPLE STENCIL DESIGN

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated